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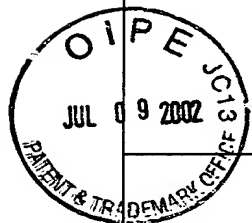
Sheet 1 of 1

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEAttorney Docket No.:  
GR 98 P 2314 PApplic. No.  
09/781,173

Applicant

Siegfried Schwarzl

Filing Date  
February 12, 2001Group Art Unit  
2824INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT  
(37 CFR 1.98(b))

## U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
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	B						
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## FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
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	L						
	M						
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ap	B	5,039,655	08/13/91	Pisharody	505	170	
ap	C	5,587,943	12/24/96	Torok et al.	365	158	
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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES   NO
ap	J	0 776 011 A2	05/28/97	Europe	_____	_____	X
ap	K	0 776 011 A3 ✓	11/19/97	Europe	_____	_____	X
ap	L	0 875 901 A2 ✓	11/04/98	Europe	_____	_____	X
ap	M	0 875 901 A3 ✓	11/03/99	Europe	_____	_____	X
ap	N	02 093 373 ✓	04/04/90	Japan	_____	_____	X

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ap	O ✓	Mark H. Kryder et al.: "Magnetic Properties and Domain Structures in Narrow NiFe Stripes", IEEE Transactions on Magnetism, Vol. Mag-16, No. 1, January 1980, pp. 99-103
ap	P ✓	D.D. Tang et al.: "Spin-Valve RAM Cell", IEEE Transactions on Magnetism, Vol. 31, No. 6, November 1995, pp. 3206-3208

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ap	J	10 004 227 A ✓	01/06/98	Japan	—	—	X
ap	K	10 162 326 A ✓	06/19/98	Japan	—	—	X
ap	L	10 190 090 A ✓	07/21/98	Japan	—	—	X
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ap	P ✓	Yu Lu et al.: "Shape-anisotropy-controlled magnetoresistive response in magnetic tunnel junctions", Appl. Phys. Lett. Vol. 70 No. 19, May 1997, pp. 2610-2612

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ap	O ✓	Haruki Yamane et al.: "Differential type giant magnetoresistive memory using spin-valve film with a NiO pinning layer", Journal of Applied Physics, Volume 83, No. 9, May 1, 1998, pp. 4862-4868
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